



**Euroopa Liit  
Euroopa Sotsiaalfond**



**Eesti tuleviku heaks**

**Toetab TÜ ja TTÜ doktorikool  
“Funktsionaalsed materjalid ja tehnoloogiad” (FMTDK)**

**ESF projekt 1.2.0401.09-0079**

# CREATION PROCESSES OF FRENKEL DEFECTS IN $\text{Lu}_3\text{Al}_5\text{O}_{12}$ AND $\text{Al}_2\text{O}_3$ SINGLE CRYSTALS .

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The formation energy of a pair of Frenkel defects exceeds the energy gap ( $E_{\text{FD}} > E_{\text{g}}$ ) in pure and doped  $\text{Al}_2\text{O}_3$ ,  $\text{MgO}$  and  $\text{Y}_3\text{Al}_5\text{O}_{12}$  single crystals, which are highly resistant against irradiation by X- or  $\gamma$ -rays. However, the creation of Frenkel defects in these crystals takes place under a swift-ion-irradiation that provides extremely high excitation density inside the tracks of heavy ions. Both the universal impact mechanism and novel nonimpact ones [1] are responsible for the radiation damage under such irradiation conditions. For instance, the energy released at the recombination of a hot (nonrelaxed) electron-hole ( $e$ - $h$ ) pair can exceed the value of  $E_{\text{FD}}$ . The latter radiation processes were revealed in  $\text{Al}_2\text{O}_3$  crystals, pure or doped with  $\text{Cr}^{3+}$ ,  $\text{Gd}^{3+}$ ,  $\text{Sc}^{3+}$  ions [2]. The present study continues such investigations in  $\text{Lu}_3\text{Al}_5\text{O}_{12}$  (LuAG) crystals irradiated for the first time by 2.14-GeV  $\text{U}^{238}$  ions (GSI, Darmstadt) at 300 K. LuAG crystals doped with different concentrations of luminescent rare-earth  $\text{Ce}^{3+}$  ions have been investigated as well.

The methods of VUV spectroscopy (exciting photons of 6-30 eV) at 6, 80 and 300 K as well as the methods of thermoactivation spectroscopy (temperature region of 6-720 K, preliminary irradiation of the samples by VUV photons or an electron beam at 6 or 300 K) allowed to detect a small amount of pre-irradiation (as-grown)  $\text{F}^+$  centers, the number of which was significantly increased in the samples irradiated with swift heavy ions. The cerium-concentration dependence on the competition between energy transfer to  $\text{Ce}^{3+}$  impurity ions or other nano-size structural defects has been analyzed in LuAG: $\text{Ce}^{3+}$  crystals at the selective photocreation of cold  $e$ - $h$ , hot  $e$ - $h$  pairs, cation excitations or the groups of some spatially correlated electronic excitations. The function mechanisms of LuAG: $\text{Ce}^{3+}$  fast scintillators are discussed. Particular attention has been placed on the formation of several spatially correlated electronic excitations by one exciting photon (i.e. multiplication process).

[1] A. Lushchik, Ch. Lushchik, M. Kirm, V. Nagirnyi, F. Savikhin, E. Vasil'chenko, *Nucl. Instr. and Meth. B* **250** (1-2), pp. 330-336, 2006.

[2] A.Lushchik, Ch.Lushchik, K.Schwartz, E.Vasil'chenko, T.Kärner, I.Kudryavtseva, V.Isakhanyan, A.Shugai, *Nucl. Instr. and Meth. B* **266**, (12-13), 2868-2871, 2008.

[3] A. Lushchik, Ch. Lushchik, T. Kärner, P. Liblik, V. Nagirnyi, E. Shablonin, A. Shugai, E. Vasil'chenko, *Radiat. Meas.*, submitted.